

EAST Search History**EAST Search History (Prior Art)**

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L3	2901	"204".clas. and ((Si silicon) with (target cathode))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/06 13:29
L4	49	L3 and relative adj density	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/06 13:29
L5	8	vickers with (silicon near4 polycrystalline)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/06 13:34
L6	41	(Hv "h.sub.v") with (silicon near4 polycrystalline)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/06 13:35
L7	7	"204".clas. and sputter \$5 and (beneficial necessary helpful) with (vickers)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/06 13:37
L8	7	"204".clas. and sputter \$5 and (beneficial necessary helpful) with (vicker's)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/06 13:37
L9	587	(silicon) with (vicker's)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/06 13:38

S1	14	(Si silicon) with (ratio) with plane with ("111") with "200"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 10:39
S2	9	("20020171123" "6193856" "6197134" "6334938" "6440278" "6743343").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 10:44
S3	29	(Si silicon) with (ratio) with plane with ("111") with "220"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 10:50
S4	63	"204".clas. and ((Si silicon) near3 (polycrystalline)) with target	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 10:59
S5	0	"204".clas. and ((Si silicon) near3 (polycrystalline)) with target with non-ordered	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 10:59
S6	0	"204".clas. and ((Si silicon) near3 (polycrystalline)) with target with ordered	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 10:59
S7	1	"204".clas. and ((Si silicon) near3 (polycrystalline)) with target with order\$3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 10:59
S8	0	"204".clas. and ((Si silicon) near3 (polycrystalline)) with target with non-orient \$3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 11:00

S9	0	"204".clas. and ((Si silicon) near3 (polycrystalline)) with target with orient\$3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 11:00
S10	0	"204".clas. and ((Si silicon) near3 (polycrystalline)) with target with "non-oriented"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 11:00
S11	0	"204".clas. and (Si silicon) with target with "non-oriented"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 11:00
S12	3	"204".clas. and (Si silicon) with "non-oriented"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 11:00
S13	0	"204".clas. and (Si silicon) with "nonoriented"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 11:01
S14	2	"204".clas. and (Si silicon) with "unoriented"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 11:01
S16	8	"204".clas. and (Si silicon) with ("111") with "220"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 11:24
S17	3	"204".clas. and (Si silicon) with (nonorient \$3 non-orient\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 11:26

S18	164	"204".clas. and (Si silicon) with (orient\$3 non-orient\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 11:27
S19	12	"204".clas. and (Si silicon) with target with (orient\$3 non-orient\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 11:27
S20	1	"204".clas. and ((Si silicon) near3 (polycrystalline)) with target	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 11:59
S21	63	"204".clas. and ((Si silicon) near3 (polycrystalline)) with target	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 11:59
S22	2	S21 and ("111" and "220")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 12:00
S23	34	S21 and density	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 12:00
S24	2	S21 and relative adj density	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 12:01
S25	4	2003-121527	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 12:02

S26	0	03-121527	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 12:02
S27	3	"03121527"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 12:02
S28	0	03-339748	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 12:03
S29	2	"03339748"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 12:03
S30	3	"2003-339748"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 12:03
S31	2	2001-319382	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 12:05
S32	0	01-319382	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 12:05
S33	0	1-319382	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 12:05

S34	65	"204".clas. and ((Si silicon) near5 (polycrystalline)) with target	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 12:56
S35	2	S34 and (relative near3 density)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 12:56
S36	12	"204".clas. and (silicon Si) with target with (relative near3 density)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 12:57
S37	55	"204".clas. and (silicon Si) with target and (relative near3 density)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/04 12:57
S38	649	(Si silicon) with ("111") with "220"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/05 09:59
S39	467	"204".clas. and ((Si silicon) with (target cathode)).ab.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/05 11:19
S40	14	S39 and (relative adj density)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/05 11:19
S41	7	S39 and (vicker "vicker's")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/05 11:20

S42	1	S40 and S41	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/05 11:20
S43	2901	"204".clas. and ((Si silicon) with (target cathode))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/05 11:21
S44	49	S43 and relative adj density	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/05 11:21
S45	45	S43 and (vicker vicker's)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/05 11:22
S46	10	S44 and S45	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/05 11:22
S47	321	S43 and polycrystalline	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/05 11:23
S48	528	silicon with (vickers adj hardness)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/05 11:35
S49	0	polycrystallin near2 silicon with (vickers adj hardness)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/05 11:36

S50	8	polycrystalline near2 silicon with (vickers adj hardness)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/05 11:36
S51	39	S43 and ((vicker vicker's) adj hardness)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/05 11:41
S52	16	(Si Silicon) with electrode same (relative adj density)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/11/06 09:31

EAST Search History (Interference)

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11/6/2009 2:00:51 PM**C:\ Documents and Settings\jberman2\ My Documents\ EAST\ Workspaces\ 10573406.wsp**